



JIANGSU CHANGJIANG ELECTRONICS TECHNOLOGY CO., LTD

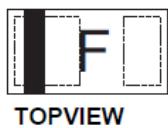
## MLDFN0.6x0.3-2L-A Plastic-Encapsulate Diodes

**DS521-30EAA02** SCHOTTKY BARRIER DIODE**FEATURE**

- Small surface mounting type
- Low reverse current and low forward voltage
- High reliability

**APPLICATION**

- High speed switching for detection
- For portable equipment:(i.e. Mobile phone,MP3, MD,CD-ROM, DVD-ROM, Note book PC, etc.)

**MARKING: F**

TOPVIEW

**MAXIMUM RATINGS ( $T_a=25^\circ\text{C}$  unless otherwise noted)**

Symbol	Parameter	Limit	Unit
$V_{RRM}$	Repetitive Peak Reverse Voltage	30	V
$V_{RWM}$	Working Peak Reverse Voltage		
$V_{R(\text{RMS})}$	RMS Reverse Voltage	21	V
$I_o$	Average Rectified Output Current	100	mA
$I_{FSM}$	Non-Repetitive Peak Forward Surge Current@ $t=8.3\text{ms}$	0.5	A
$P_d$	Power Dissipation	100	mW
$R_{\theta JA}$	Thermal Resistance from Junction to Ambient	1000	°C/W
$T_J$	Junction temperature	125	°C
$T_{stg}$	Storage Temperature	-55 ~ +150	°C

**ELECTRICAL CHARACTERISTICS ( $T_a = 25^\circ\text{C}$  unless otherwise specified)**

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Reverse breakdown voltage	$V_{(BR)}$	$I_R=50\mu\text{A}$	30			V
Reverse current	$I_R$	$V_R=10\text{V}$			10	$\mu\text{A}$
		$V_R=30\text{V}$			50	$\mu\text{A}$
Forward voltage	$V_F$	$I_F=10\text{mA}$			0.38	V
		$I_F=100\text{mA}$			0.80	V

